



# SE05S3BPDB

## ESD PROTECTION DIODE

### FEATURES

- Bi-directional ESD protection
- IEC61000-4-2 25KV(Contact), 30KV(air)
- Ultra small SMD package:0201
- Operating voltage: 5V
- Suffix "H" indicates Halogen-free parts, ex. SE05S3BPDBH

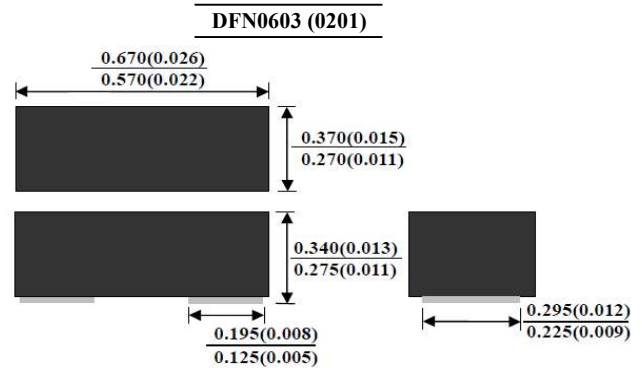
### APPLICATIONS

- Computers and peripherals
- High speed data lines
- Audio and video equipment
- Cellular handsets and accessories
- Portable electronics

### MECHANICAL DATA

Case : DFN0603(0201) standard package  
 Terminals : Au plated, Solderable per MIL-STD-750,  
 method 2026  
 Meet MSL 1 requirement  
 Epoxy: UL 94V-O rate flame retardant

### PIN CONFIGURATION



Dimensions in inches millimeters and (inches)

### Maximum Ratings (Rating at 25°C ambient temperature unless otherwise specified)

Parameter	Symbol	Value	Units
IEC 61000-4-2 ESD Voltage Air Model	$V_{ESD}$	±30	kV
Contact Model		±25	
Peak Pulse Power $t_p=8/20$ us	$P_{PP}$	50	W
Maximum Peak Pulse Current $t_p=8/20$ us	$I_{PP}$	3.5	A
Operating Junction Temperature	$T_j$	-55 to +125	°C
Storage Temperature Range	$T_{stg}$	-55 to +150	°C



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### *Electrical Characteristics ( $T_a = 25\text{ }^\circ\text{C}$ unless otherwise specified)*

Parameter	Test conditions	Symbol	Min	Typ	Max	Unit
Reverse stand off voltage	-	$V_{RWM}$	-	-	5	V
Reverse leakage current	$V_{RWM}=5V$	$I_R$	-	-	10	nA
Reverse breakdown voltage	$I_T=1mA$	$V_{(BR)}$	5.6	-	9.0	V
Clamping voltage	$I_{pp}=1A, t_p=8/20\ \mu s$	$V_C$	-	-	12	V
	$I_{pp}=3.0A, t_p=8/20\ \mu s$	$V_C$	-	-	17	V
Clamping voltage	$I_{pp}=-5.0A, TLP=0.2/100ns$	$V_C$		-15		V
	$I_{pp}=5.0A, TLP=0.2/100ns$	$V_C$		15		V
	$I_{pp}=-30A, TLP=0.2/100ns$	$V_C$		-20		V
	$I_{pp}=30, TLP=0.2/100ns$	$V_C$		20		V
Junction capacitance	Between I/O Pin and GND $V_R=0V, f=1MHz$	$C_j$	-	3	10	pF
Dynamic Resistance	$T_p=100ns$	$R_D$	-	0.23	-	$\Omega$

1) TLP Settings:  $t_p=100ns, t_r=0.2ns, ITLP$  and  $VTLP$  averaging window:  $t_1=70ns$  to  $t_2=90ns$ .

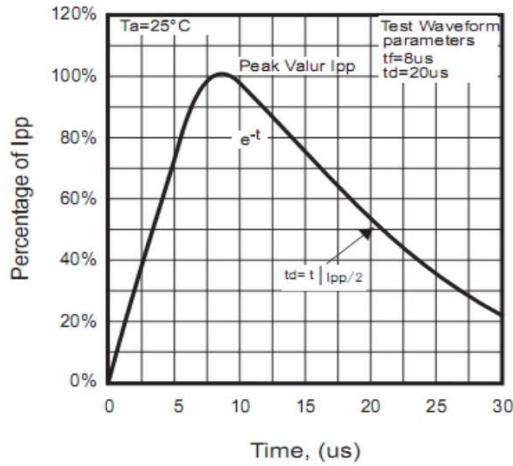
2) Dynamic resistance calculated from  $I_{TLP}=-5A$  to  $I_{TLP}=-30A$  and  $I_{TLP}=+5A$  to  $I_{TLP}=+30A$



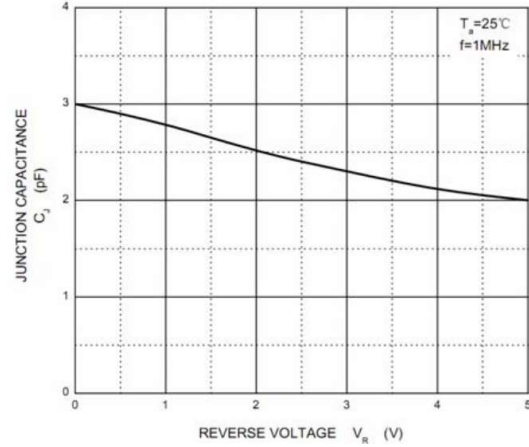
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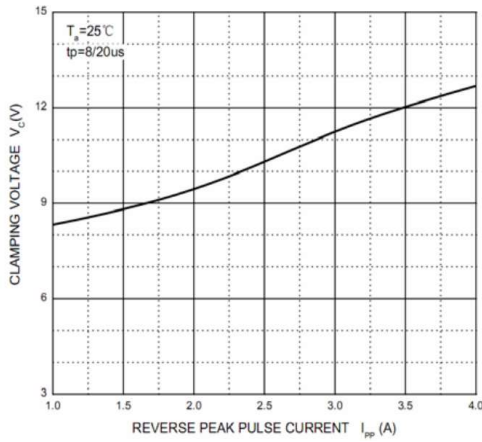
### RATINGS AND CHARACTERISTIC CURVES



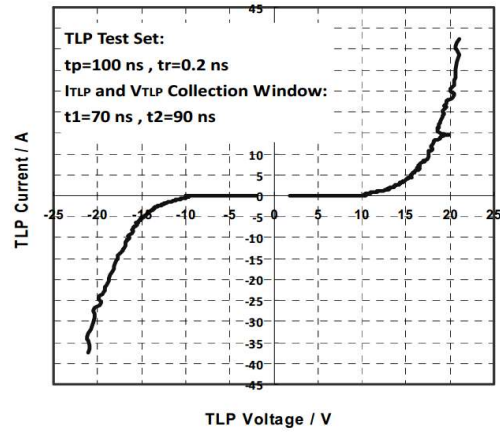
**Fig.1 8/20  $\mu$ S Peak Pulse Current Wave From Acc. IEC 61000-4-5**



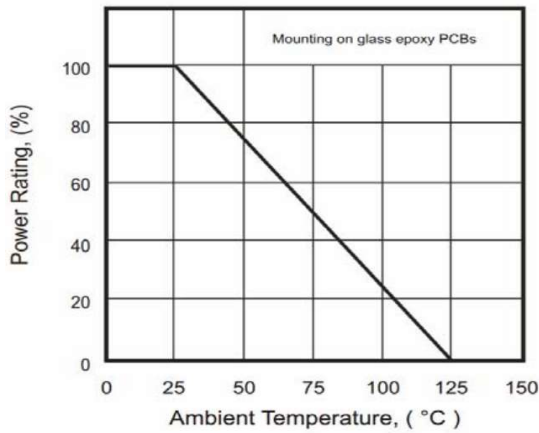
**Fig.2 Typical Capacitance Between Terminals Characteristics**



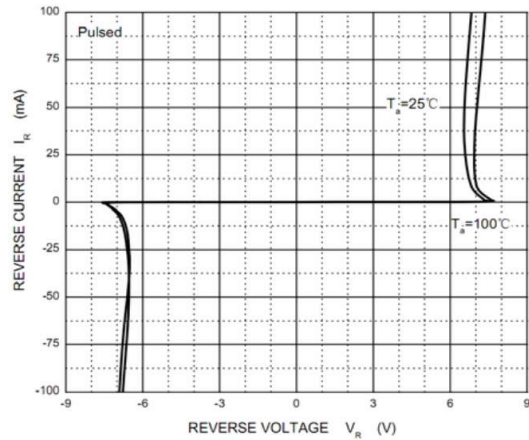
**Fig.3 Clamping Voltage vs Peak Pulse Current**



**Fig.4 TLP Measurement**



**Fig.5 Power Derating Curve**



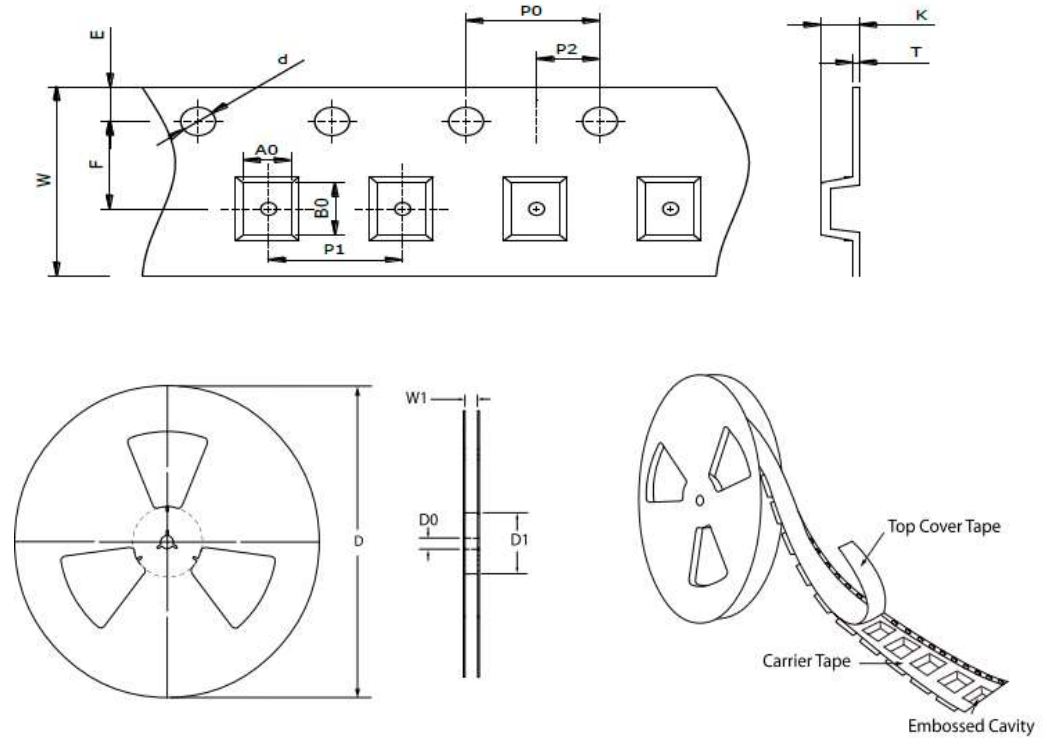
**Fig.6 Reverse Characteristics**



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### TAPE & REEL SPECIFICATION



Item	Symbol	DFN0603 (0201)
Carrier width	A <sub>0</sub>	0.37 ± 0.05
Carrier length	B <sub>0</sub>	0.67 ± 0.05
Carrier depth	K	0.50 ± 0.05
Sprocket hole	d	1.50 ± 0.10
Reel outside diameter	D	178.00 ± 2.00
Feed hole width	D <sub>0</sub>	13.00 ± 0.20
Reel inner diameter	D <sub>1</sub>	MIN. 54.00
Sprocket hole position	E	1.75 ± 0.10
Punch hole position	F	3.50 ± 0.10
Sprocket hole pitch	P <sub>0</sub>	4.00 ± 0.10
Punch hole pitch	P <sub>1</sub>	4.00 ± 0.10
Embossment center	P <sub>2</sub>	2.00 ± 0.10
Overall tape thickness	T	0.18 ± 0.05
Tape width	W	8.00 ± 0.20
Reel width	W <sub>1</sub>	MAX. 13.50

### ORDER INFORMATION

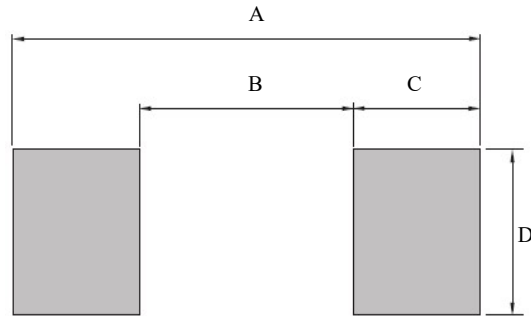
Package	Marking Code	Reel Size	Quantity
DFN0603 (0201)	I	7"	10,000



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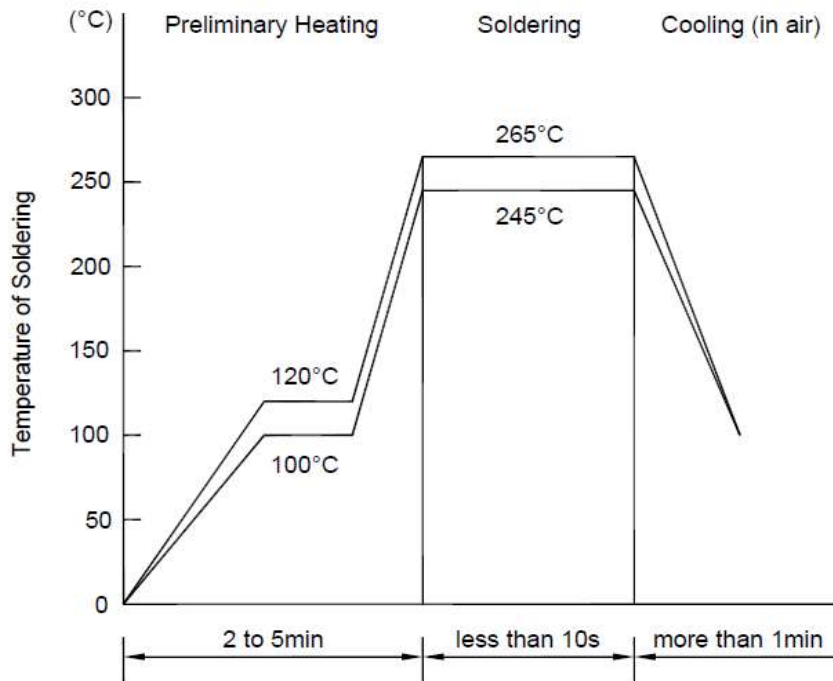
### SUGGESTED SOLDER PAD LAYOUT



PACKAGE	A	B	C	D
DFN0603 (0201)	0.64	0.20	0.22	0.36

### CONDITION OF SOLDERING

#### Recommended condition of flow soldering

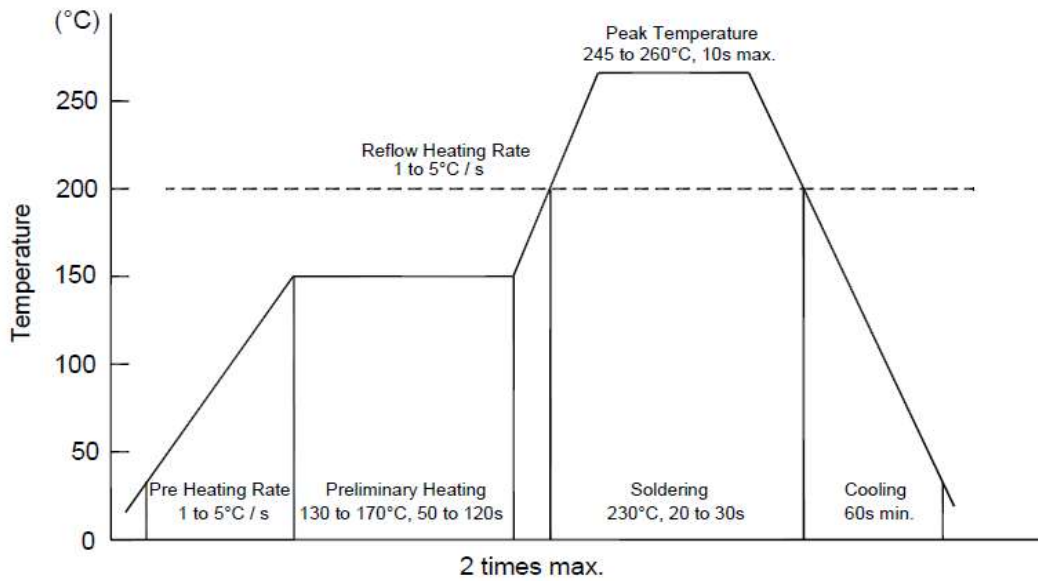




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### Recommended condition of reflow soldering



Recommended peak temperature is over 245°C. If peak temperature is below 245°C, you may adjust the following parameters; time length of peak temperature (longer), time length of soldering (longer), thickness of solder paste (thicker)

### Condition of hand soldering

Temperature: 370°C

Time: 3s max.

Times: one time